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Understanding the Dopant Induced Effects on SFX-MeOTAD for Perovskite Solar Cells: A Spectroscopic and Computational Investigation

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SFX-MeOTAD [2,2′,7,7′-Tetrakis(N,N-di(4-methoxyphenyl)amino)-spiro-(fluorene-9,9′-xanthene)] (also known as X60) has emerged as a cost-effective alternative to the ubiquitous, but excessively-expensive, spiro-MeOTAD hole transport material (HTM) in perovskite solar cells. Using its pre-oxidised dicationic salt, SFX-(TFSI), a controlled concentration dependent conductivity tuning of this HTM without the requirement of air (oxygen) exposure is carried out. This study details the modifications in optical and electrical properties of this low cost HTM as a function of concentration of the dicationic salt (0-100 mol %) using UV-Vis absorption and electrical conductivity measurements. X-ray absorption and photoelectron spectroscopic investigations have been carried out to elucidate the role of the dicationic salt on the enhanced electronic properties of SFX-MeOTAD. By incorporating the dicationic SFX-(TFSI), it was shown that the conductivity of SFX-MeOTAD increased by 4 orders of magnitude from 2.55 × 10⁻⁶ S cm⁻¹ to 9.4 × 10⁻⁴ S cm⁻¹ using an optimal dopant concentration of 20.5 mol %. The degree of oxidation of SFX-MeOTAD was determined through UV-Vis absorption and consolidated by the computational calculations. XPS study reveal that doping SFX-MeOTAD with SFX(TFSI): results not only in oxidation of the HTM but also leads to variation in the local chemistry around carbon and nitrogen which directly influence the conductivity of the doped films. NEXAFS studies indicates that doping enhances the aromatic nature of the molecule initially but increasing the dopant concentration further affects the aromaticity and possibly the π stacking, similar to the trend seen in dopant concentration dependent conductivity of the SFX-MeOTAD films. These findings have implications on the choice of dopant concentration and counterions more generally for triarylamine based HTMs.

1. Introduction

Perovskite solar cells (PSCs) evolved from dye-sensitised solar cells (DSSCs) after Kojima et al utilised a lead halide perovskite as a sensitizer in the DSSC.1 Following on from this, there has been a surge of research interest in PSCs due to extraordinary material properties e.g. tuneable bandgap of the absorber material, long charge carrier diffusion lengths and lifetimes and lower production costs due to easy manufacturing via solution processing.2–3 To date, the highest power conversion efficiency (PCE) recorded for PSCs is 25.5 %.4 Perovskites are ambipolar in nature and hence can be used in different device architectures.5

PSCs are layered devices that contains the perovskite absorber sandwiched between a n-type electron transport layer (ETL) and a p-type hole transport layer (HTL). The role of the hole transport layer is to transport the photogenerated holes, increase selectivity and, reflectivity of the top contact and increase the internal quantum efficiency of the PSC.6 An appropriate hole transport material (HTM) must meet certain criteria such as high thermal stability, optimum energy level alignment with the perovskite material and good solubility for solution processing.7 One of the most common HTMs used in PSCs is 2,2′,7,7′-tetrakis[N,N-di(4-methoxyphenyl)amino]-9,9′-spirobifluorene (spiro-MeOTAD), however it has a relatively low conductivity with varying values of 2×10⁻⁶ S cm⁻¹ and 2.5×10⁻⁵ S cm⁻¹ reported in literature.8,9 In order to improve its conductivity chemical dopants are used. These dopants are p-type which are used to increase the concentration of charge carriers that in turn increases the conductivity of the HTM.10–15 The most prevalent dopant used in spiro-MeOTAD is lithium bis(trifluoromethanesulfonyl)imide (LiTFSI). The use of LiTFSI however does not directly oxidise spiro-MeOTAD, and after mixing, the HTM must be exposed to the air in order to be oxidised.16,17 This is an issue as it is difficult to control and regulate the degree of the oxidation of the spiro-MeOTAD. This production of unpredictable variations of the oxidised spiro-

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MeOTAD has been shown to have an effect on the repeatability/reproducibility of PSC performance and stability. LiTFSI also promotes pinhole formation in spiro-MeOTAD, which has detrimental effects on the performance of PSCs (e.g., PSCs without pinholes in the HTL are shown to have 10 times longer life time as compared to those with pinholes). Applying other dopants such as cobalt complexes Tris(2,5-dipyridine)copper(II) (bcpm), tris(2,5-dipyridine)cobalt(III) tris(bis(trifluoromethane)sulfonimide) (FK102), and tris(2,5-dipyridine)-4-tert-butylpyridine)cobalt(III) tris(bis(trifluoromethane)sulfonimide) (FK209), benzoyl peroxide (BPO) and H2PO4, also do not result in direct oxidation of spiro-MeOTAD and require co-doping with LiTFSI. These dopants form the spiro-MeOTAD radical cation, however, for an effective charge generation a TFSI counter anion is required. Other p-type dopants are metal complexes. One such example is the copper (II) complex, bis[2,2',7',2''-terphenyl]-dipyridine copper(II) bis[bis(trifluoromethylsulfonyl)imide] [Cu(bcpm)]2, in which the TFSI counter anion was used to increase the solubility of the (II) complex in organic solvents. Another metal complex used is molybdenum tris(1-trifluoroacetyl)-2,3-dihydroxyethyl-1,2-dithiolene (Mo(tdf-COCF3)3), which exhibits reversible reduction to its stable monoanion. This monanion oxidises spiro-MeOTAD to its monoanocation and thus explains why no large repeatability/reproducibility of PSCs were demonstrated to have the requirement of air exposure and hence addresses the unpredictability of producing different variations of oxidised spiro-MeOTAD. Spiro-MeOTAD is also costly due to the tedious multistep synthesis of the spiro core, thus explaining why no large-scale commercial deployments of perovskite solar cells using this HTM exist. An alternative HTM that contains a spiro[fluorene-9,9'-xanthene] core obtained from one-pot reaction of fluorenone and phenol in the presence of methane sulfonic acid without any solvent, is SFX-MeOTAD. Different concentrations of SFX-MeOTAD, SFX-TFSI2, and silver bis(trifluoromethanesulfonylimide) were mixed in dry dichloromethane under nitrogen. The mixture was stirred for 24 hours at room temperature. The resulting mixture was then diluted with methylene chloride, filtered and the solvent was removed by rotary evaporation. This residual solid dissolved in dichloromethane and then precipitated in dry diethyl ether twice. The resulting powder was dried under vacuum and composition confirmed by CHN elemental analysis (%): Calculated C 56.66, H 3.80, N 4.66. Result: C 56.50, H 3.68, N 4.59.

2.2. Deposition of SFX(TFSI)2 doped SFX-MeOTAD films

Different concentrations [0-100 mol%] of SFX(TFSI)2 were mixed with SFX-MeOTAD in anhydrous chlorobenzene to a combined concentration of 0.15M. To this 0.12M 4-tert-butylpyridine was added before spin coating on cleaned glass (for absorbance and conductivity measurements) or FTO coated glass (for XPS and NEXAFS measurements) at 2000 rpm for 1 minute. For conductivity measurements aluminium electrodes (~80 nm) were deposited by thermal evaporation (~10 6 mbar) on doped and undoped SFX-MeOTAD thin films coated on glass.

2.3. Characterisation Techniques

Elemental analyses of SFX-MeOTAD and SFX(TFSI)2 were carried using a Carlo Erba CE1108 Elemental Analyser. For evaluating the conductivity of SFX-MeOTAD films doped with varying concentrations of SFX(TFSI)2 (0-100 mol%), I-V measurements were carried out in the dark inside N2 filled glovebox via two-point probe method using Keithley 4200-SCS Parameter Analyser. For each dopant concentration an average of four I-V measurements have been recorded. Using the inverse gradient of the I-V plots, the area between the electrodes and thickness of the films the conductivity was evaluated. The film thickness was measured in air using Digital Instruments, Dimension 3100, Atomic Force Microscope (AFM) in tapping mode (using TESP-V2 probes and Nanoscope III software) with ten measurements per sample used to determine the average thickness. In order to handle the AFM data, the WSXM software was used. Absorbance of SFX-MeOTAD thin film samples with different SFX(TFSI)2 doping
concentration (0-100%) was studied using UNICAM UV 300 spectrophotometer in the range 290-1100 nm. The electronic properties of the undoped and SFX-(TFSI)$_2$ doped SFX-MeOTAD films were investigated using XPS with a load-locked KRATOS XSAM-800 instrument equipped with a dual anode X-ray source using a Mg Ka (1253.6 eV) excitation source. For C1s, F1s, O1s and N1s core levels, photoelectrons were collected using high magnification analyser more from the smallest possible area on the specimen. CasaXPS version 2.3.16 software was used for analysing the XPS data. NEXAFS experiments were performed at the beam-line 8-2 of the Stanford Synchrotron Radiation Lightsource of SLAC National Accelerator Laboratory.\textsuperscript{26} The samples were vacuum sealed and packed with molecular sieves during transport to carry out XPS and NEXAFS experiments. The samples were mounted on an aluminium stick with a conductive carbon tape and measurements were performed under ultrahigh vacuum conditions (< 1 x 10$^{-9}$ Torr). The energy of the incident beam was calibrated at the carbon dip (284.7 eV) arising from the contaminations in the beamline optics. Beamline slits and the pass energy of the analyser were set to achieve a total energy resolution of 0.3 eV. To eliminate effects of sample orientation on the intensities of the resonances, the C and N K-edge spectra were acquired in total electron yield (TEY) mode at 54.7° (magic angle) incidence of the soft X-ray beam between 280.0 to 330.0 eV and 380.0 to 440.0 eV, respectively. The spectra were then normalised to a linear background following the protocol developed by Wang et al.\textsuperscript{27,28} The incoming flux ($I_{in}$) was measured using a gold mesh in the beamline and the signal was divided by the incident flux for normalisation. Pre- and post-edge normalisation were carried out from 275-285 eV and 320-330 eV for the C K-edge and the edge jump was normalised to unity. C and N K-edge NEXAFS spectra of the pristine SFX-MeOTAD and SFX-(TFSI)$_2$ doped SFX-MeOTAD films were probed individually to understand the variation in electronic properties as a function of dopant concentrations.

2.4. Computational Details

The molecular structures of SFX-MeOTAD and its oxidised forms i.e. SFX-MeOTAD$^+$, SFX-MeOTAD$^{2+}$ and SFX-MeOTAD$^{4+}$ were optimised in chlorobenzene solvent using the PBE0 functional and the 6-311G(d,p) basis set.\textsuperscript{29,30} The calculations were carried out using Gaussian 16.\textsuperscript{31} The solvation model used in the calculations was the default IEF-PCM solvation model.\textsuperscript{32} The changes to the electronic structure and the absorption spectra, which is instigated by the oxidation from the SFX-(TFSI)$_2$, was investigated using TDDFT calculations that also employed the PBE0 functional and the 6-311G(d,p) basis set. The solvation model used was the default IEF-PCM model in chlorobenzene. For all the species, 60 excitation states were calculated.

3. Results and Discussion

3.1 Electrical and Optical properties of SFX(TFSI)$_2$ doped SFX-MeOTAD

Conductivity values of SFX-MeOTAD films doped with varying molar percentages of SFX-(TFSI)$_2$ were evaluated from I-V measurements carried out in the dark inside a N$_2$ filled glovebox using a two-point probe method. As shown in Figure 2 (a) and (b), pristine SFX-MeOTAD has a rather low conductivity of 2.55 x 10$^{-8}$ S cm$^{-1}$ and as the molar concentration of SFX-(TFSI)$_2$ is increased, the conductivity improves. At a dopant concentration of 20.5 mol% of SFX-(TFSI)$_2$, the conductivity of SFX-MeOTAD was observed to increase by four orders of magnitude to a value of 9.43 x 10$^{-4}$ S cm$^{-1}$. The conductivity values of undoped SFX-MeOTAD reported in the literature lie within a wide range 1.96 x 10$^{-6}$ S cm$^{-1}$ and 1.1 x 10$^{-4}$ S cm$^{-1}$, similar to conductivity values in a wide range reported for undoped spiro-MeOTAD.\textsuperscript{22,24} It is important to note that, in the present study, the conductivity measurements were carried out in the dark inside the N$_2$ glovebox to avoid any photo-oxidation of the SFX-MeOTAD in air. Recent work utilising pre-oxidised SFX-MeOTAD reported in the literature quoted an increase in conductivity by 2 orders of magnitude from 1.96 x 10$^{-6}$ S cm$^{-1}$ to 8.84 x 10$^{-4}$ S cm$^{-1}$ upon increasing the doping concentration from 0% to 20%.\textsuperscript{24} The work using spiro-(TFSI)$_2$ doping in Spiro-MeOTAD, on the other hand, reported an increase in conductivity by 5 orders of magnitude, increasing from 2 x 10$^{-8}$ S cm$^{-1}$ to 1.43 x 10$^{-3}$ S cm$^{-1}$ upon increasing the dopant concentration from 0% to 14%.\textsuperscript{8} This increase in conductivity by 5 orders of magnitude is analogous to the level of conductivity

![Figure 1](image-url)
increase that is observed in the present study (from $2.55 \times 10^{-6}$ S cm$^{-1}$ to $2.2 \times 10^{-4}$ S cm$^{-1}$), however a higher doping concentration of 32.2 mol% of SFX-(TFSI)$_2$ is required for SFX-MeOTAD. From Figure 2 (b) it was observed that the conductivity increased linearly and started to plateau after 20.5 mol% concentration. Using a linear fit, it was found that the point of inflection lies ~ 20.5 mol%, which is the optimal dopant concentration for SFX-MeOTAD. Figure 2 (c) shows the absorbance spectra of undoped and doped SFX-MeOTAD. The undoped SFX-MeOTAD film has a maximum absorbance at ca. 387 nm and the peak decreases as the concentration of SFX-(TFSI)$_2$ increases. The measured maximum absorbance is in agreement with the previous reported values in the range 367-388 nm for SFX-MeOTAD.\textsuperscript{21,22} Spiro-MeOTAD shows absorbance bands at ca. 385 nm showing that SFX-MeOTAD exhibits similar optical properties as spiro-MeOTAD.\textsuperscript{33} As the concentration of SFX-(TFSI)$_2$ increases, the absorption band at 387 nm decreases, and there is an increase in bands at around 520 nm and 680 nm. This corresponds to the production of the oxidised radical species [e.g., SFX-MeOTAD\textsuperscript{+1} and SFX-MeOTAD\textsuperscript{+2}].\textsuperscript{22,24} This phenomenon is also reported in spiro-MeOTAD with peaks appearing at 520-524 nm and 687-690 nm upon oxidation.\textsuperscript{8,10,14-16,34} When measured on thin films, the absorption peak of spiro-MeOTAD at ca. 522 nm increases as the molar% of spiro-(TFSI)$_2$ increases and there is also an increase in the peak ca. 700 nm.\textsuperscript{35} Recently, the absorbance spectrum of spiro-(TFSI)$_2$ single crystals dissolved in acetonitrile were studied in a wide wavelength range (300 – 2000) and reported to show peaks at 371 nm, 521 nm, 691nm, 908 nm and 1527 nm.\textsuperscript{36} To understand the changes induced by the oxidation processes on the electronic structure and absorption spectrum and to optimise the geometries of the possible oxidised species of SFX-MeOTAD, DFT and TD-DFT computational calculations were carried out. The optimised structure of neutral SFX-MeOTAD shows that both the xanthene and fluorene units of the spiro[fluorene-9,9'-xanthene] core are planar, and the appended triarylamine units are not planar, but are in a propeller orientation (see S1 in Supporting Information (SI)). As the neutral SFX-MeOTAD is oxidised to the +1 species it leads to the formation of a doublet ground state and when this is further oxidised to the +2 species an open shell triplet state is formed. The triplet state for the +2 species was calculated to be 7.08 kcal/mol more stable than the singlet state. The nature of a possible +4 species that might form in the oxidation process was also calculated and it was found that the triplet state was more stable than the singlet state by 13.97 kcal/mol for this oxidation state.

\begin{table}
\centering
\caption{Main optimised geometrical parameters (Mean values on four quasisymmetric units) of SFX-MeOTAD (Neutral) and its oxidised forms (1\textsuperscript{+}, 2\textsuperscript{+}, 4\textsuperscript{+}).}
\begin{tabular}{lllll}
\hline
Parameter\textsuperscript{a} & Neutral (vacuo) & Neutral (chlorobenzene) & 1\textsuperscript{+} (chlorobenzene) & 2\textsuperscript{+} (chlorobenzene) & 4\textsuperscript{+} (chlorobenzene) \\
\hline
C\textsubscript{2}C\textsubscript{2} & 1.528 & 1.523 & 1.520 & 1.520 & 1.530 \\
C\textsubscript{2}C\textsubscript{3} & 1.395 & 1.396 & 1.396 & 1.388 & 1.391 \\
C\textsubscript{2}C\textsubscript{4} & 1.389 & 1.389 & 1.390 & 1.393 & 1.393 \\
C\textsubscript{3}C\textsubscript{4} & 1.389 & 1.392 & 1.392 & 1.400 & 1.394 \\
C\textsubscript{3}C\textsubscript{5} & 1.400 & 1.403 & 1.403 & 1.408 & 1.402 \\
C\textsubscript{4}N\textsubscript{3} & 1.415 & 1.408 & 1.407 & 1.392 & 1.411 \\
C\textsubscript{5}C\textsubscript{6} & 1.380 & 1.380 & 1.379 & 1.375 & 1.376 \\
C\textsubscript{6}C\textsubscript{7} & 1.395 & 1.394 & 1.395 & 1.396 & 1.396 \\
C\textsubscript{7}C\textsubscript{8} & 1.362 & 1.365 & 1.363 & 1.359 & 1.354 \\
N\textsubscript{3}C\textsubscript{10} & 1.416 & 1.414 & 1.415 & 1.416 & 1.403 \\
N\textsubscript{4}C\textsubscript{12} & 1.409 & 1.414 & 1.413 & 1.414 & 1.393 \\
Φ (C\textsubscript{2}C\textsubscript{3}N\textsubscript{3}C\textsubscript{11}) & 124 & 142 & 143 & 148 & 139 \\
Θ & 116 & 116 & 116 & 116 & 116 \\
\hline
\end{tabular}
\end{table}

\textsuperscript{a}Bond lengths are in angstroms and bond angles are in degrees

Figure 2 (a) Current-voltage characteristics of SFX-MeOTAD films doped with different concentrations (mol%) of SFX-(TFSI)$_2$, (b) Conductivities of SFX-MeOTAD films as a function of SFX-(TFSI)$_2$ concentrations. The dotted lines showing linear fit to the data with point of inflection ~ 20.5% (c) Absorbance spectra of thin films of SFX-MeOTAD doped with different concentrations (mol %) of SFX-(TFSI)$_2$. The 0% sample is undoped SFX-MeOTAD film where as 100% corresponds to pure SFX(TFSI)$_2$ film.
Figure 1 (a) shows the label assignment and the geometrical parameters of the optimised species of SFX-MeOTAD and its oxidised forms (1\textsuperscript{+}, 2\textsuperscript{+}, 4\textsuperscript{+}). The optimised structure of neutral SFX-MeOTAD in vacuo is compared to that in chlorobenzene solvent, as given in Table 1 (column 2 and 3), slight variations in the bond lengths, the dihedral angle (\(\Phi\)) (which shows the out of plane alterations of the phenyl-OMe groups in relation to the spiro[fluorene-9,9'xanthene] core), and the angle of the OMe group that protrudes from the phenyl group, are observed. Nonetheless, the effect of solvent was anticipated to be significant in the calculated spectra of the oxidised species. Thus, all the DFT and TD-DFT calculation for the oxidised species have been carried out in chlorobenzene solvent. Further investigation shows that there are variations in the geometries of the different oxidised states in the solvent as compared to that in vacuo. As the level of oxidation increases, the spiro[fluorene-9,9'-xanthene] core reacts by constricting the C7-O8 bond (1.365 Å in the neutral species and 1.354 Å in the +4 species). There is also the shrinking of the C7-C2 from the neutral species to the +2 species but the length of the same bond increases when oxidised to +4. The C2-C7 bonds lengthen from neutral to +4. It can however be seen that the C7-N9 bond decreases from neutral to +2 but increases when further oxidised to the +4. There is an increase in \(\Phi\) angle when going from the neutral to the +2 but then decreases when going into the +4 state. There was no change in the OMe-phenyl angle as the oxidation state was increased.

An isosurface representation of the molecular frontier orbital of neutral SFX-MeOTAD is shown in Figure 3 (a full table of energies can be found in SI; see S2). For the neutral species there are two quasi-degenerate highest occupied molecular orbitals (HOMO/HOMO-1) that are delocalised across the fluorene core of the molecule and the triarylamine groups.

**Figure 3:** Isodensity plot showing the frontier orbitals of neutral SFX-MeOTAD (a) HOMO/HOMO-1, (b) HOMO-2/HOMO-3, (c) LUMO/LUMO+1, (d) LUMO+10

**Figure 4:** Schematic representation of the molecular frontier orbitals of SFX-MeOTAD and its oxidised species with orbital energies given below in eV.
attached (HOMO), and also due to the contribution of the lone pairs on the O atom within the spiro[fluorene-9,9'-xanthene] core, lone pairs from the nitrogen atoms and the phenyl ligands into the top of the molecule (HOMO-1) (see Figure 3 (a)). When going down in energy to the HOMO-2 and HOMO-3 energy levels it can be seen that the orbitals are delocalised within the phenyl ligands and the nitrogen lone pairs contributing to the delocalisation (Figure 3 (b)).

The two lowest unoccupied molecular orbitals (LUMO/LUMO+1) show π* character (Figure 3 (c)), the delocalisation is spread across the spiro[fluorene-9,9'-xanthene] core into the phenyl ligands attached to the xanthene part of the core and at higher energy levels, such as LUMO+10, the orbitals are localised in the outer N-phenyl-OME ligands (Figure 3 (d)). The HOMO energy level was calculated to be -4.87 eV and is in good accordance with both experimental and other computational values reported for SFX-MeOTAD (experimental value of -5.16 eV and computational value of -5.11 eV and -5.61 eV). Deng et al also calculated the HOMO-LUMO gap was calculated as 3.85 eV computationally and using the absorbance onset for pristine SFX-MeOTAD from Figure 2 (c) the experimental HOMO-LUMO gap was calculated as 2.96 eV. The HOMO-LUMO gap of SFX-MeOTAD has been determined experimentally by other studies to be 2.96 eV and 3.05 eV and computationally the energy gap has been calculated to be 3.10 eV and 5.45 eV. When oxidised to the +1 i.e. SFX-MeOTAD+, species, a doublet ground state is formed and the orbitals within this are split into α and β manifolds that have different spatial wave functions and so this results in different energies for each manifold as seen in Figure 4. The HOMO in the α manifold is stabilised by 0.74 eV with respect to its β manifold counterpart, and is almost degenerate and corresponds to the HOMO-1 of the neutral species. It can be seen that the HOMO and LUMO gap in the α manifold is 3.33 eV. The electron has been removed from the β orbital and so contains the HOMO-LUMO of the monocation species which are delocalised in the spiro[fluorene-9,9'-xanthene] core and the (N-phenyl-OME)2 ligands that protrude from the core. The +2 species, i.e. SFX-MeOTAD4+ is in a triplet state that has two singly occupied orbitals in the α manifold and are quasi-degenerate and a HOMO-LUMO gap of 3.77 eV. The HOMO/HOMO-1 in the α manifold are now localised similarly to the HOMO/HOMO-1 of the neutral SFX-MeOTAD species but there is more localisation of the orbitals in one of the N-phenyl-OME ligands that is part of the xanthene core than the other. The LUMO of the α manifold corresponds to the LUMO of the neutral and +1 species as the orbitals are localised in the fluorene part of the spiro[fluorene-9,9'-xanthene] core. The HOMO/HOMO-1 shows that the orbitals are localised in half of the SFX-MeOTAD molecule and the LUMO show localisation similar to the LUMO of the monocation and neutral species.

Within the β manifold, the HOMO/HOMO-1 has the same nature as the HOMO-1/HOMO-2 of the neutral species whereas the LUMO/LUMO+1 corresponds to the HOMO/HOMO-1 of the neutral SFX-MeOTAD. The +4 species, i.e. SFX-MeOTAD4+, exists in a triplet state, which is more favourable than the singlet state for this species. This gives rise to two singly occupied molecular orbitals and with a gap of 1.66 eV between the HOMO and HOMO-1 in the α manifold. These have a character that is similar to the HOMO/HOMO-1 of the neutral, although there is more delocalisation of the orbital in one of the triarylamine branches of the lower fluorene section of the central core than the other. The HOMO-LUMO gap of the α manifold was calculated to be 2.28 eV. In the β manifold, the HOMO-3 where the electron sits lie 1.72 eV lower than the HOMO-2 orbital (see S3 for the HOMO-LUMO frontier orbitals of each oxidation state in the α and β manifolds).

There has always been great interest in the optical properties of doped HTMs to ascertain the oxidation states that contribute to particular absorptions. Figure 5 gives a comparison of experimental and computational absorption spectra of undoped (neutral) SFX-MeOTAD. The calculated spectrum (red curve in Figure 5) showed an absorption maximum at 400 nm compared to the experimentally measured 367 nm in chlorobenzene solution (magenta curve in Figure 5) and 387 nm when measured on a thin film (blue curve in Figure 5), providing reasonable agreement (red shifted by 0.28 eV compared to solution and 0.10 eV compared to the thin film) between the calculated and experimental bands. The absorbance of SFX-MeOTAD in its neutral state has been investigated by Deng et al with maximum reported at 348 nm and 403 nm using different functional methods. Sun et al carried out a study using the PBE33 method and the 6-31G* basis set for SFX-MeOTAD and maximum absorbance was reported at 346 nm in agreement with the value obtained in the present study. Other experimental absorption maxima values of 367 nm in
dichloromethane $^{21}$ and 389 nm in toluene solvent $^{22}$ whereas for thin film have been reported at 358 nm. $^{23}$ It has been reported that SFX-MeOTAD also absorbs at ca. 300 nm. $^{22}$ In this study, though this was not observed in the thin film experimental UV-Vis measurements, a peak was observed at 308 nm in the experimental solution measurements. When compared to the computational value of 308 nm, there is no deviation between the experimentally measured value and the absorbance observed computationally. This peak was not observed in the thin film samples as the thin films are deposited on glass substrates. However, a small absorbance between ca. 500-600 nm and 700-800 nm were observed in the measured absorbance curve of the SFX-MeOTAD film without any added SFX[(TFSI)$_2$] (blue curve in Fig. 5), which are associated to photo-doping in the presence of oxygen that might have occurred during transferring the samples from glovebox to UV-Vis spectrophotometer. In the solution samples, a small peak is observed at ca. 890 nm for all solution samples, but this is due to possible debris interfering with the beam inside the spectrophotometer.

From the calculated TD-DFT eigenvalues the transitions that are involved in the band centred at 400 nm are from the HOMO to the LUMO and shows strong local excitation character and also corresponds to π → π* transitions. Whereas the transitions from the HOMO/HOMO-1 to the LUMO+11 and LUMO+8 result in a peak at 308 nm with a predominant charge transfer (CT) character but also some local excitation character at one of the triarylamine groups bonded to the xanthene part of the core and both triarylamine groups attached to the fluorene part of the core. This peak was found to be more intense than that found at 400 nm (see S4 for all MO isodensity plots of transitions mentioned).

Further to this, the experimental and calculated spectra of the +2 species were compared and benchmarked with each other. This spectrum of the pristine SFX-(TFSI)$_2$ dicationic salt is shown in Figure 6. Computationally it was shown the peaks that correspond to this species appear at 389 nm, 459 nm and 681 nm. From analysing the TD-DFT eigenvalues, it can be inferred that the transition from low-lying HOMO orbitals HOMO-13 to the LUMO+1 in the β manifold corresponds to the 459 nm peak. Transitions in the α manifold, HOMO-1 to the LUMO also corresponds to the band at 459 nm, whereas the transitions from the HOMO-7/HOMO-5 orbitals to the LUMO/LUMO+1 correspond to the band at 681 nm in the β manifold. These transitions show π → π* character and predominantly local excitation character but there is some partial CT character. Further analysis of the eigenvalues shows that a transition from the HOMOα to the LUMO+3α represents the peak at 389 nm with a mixture of local excitation and CT character and when comparing this to the experimental data which shows an absorbance peak at 386 nm there is a very good correlation between the experimental and computational values. The experimental spectrum shows peaks at 520 nm and 703 nm, which again provides good agreement between the calculated (blue shifted by 0.3 eV for peaks found at ca. 500 nm and <0.1 eV for the peaks at ca. 700 nm) and experimental thin film bands. When measure in solution, the absorbance bands were measured as ca. 350 nm, 524 nm and 709 nm (0.35 eV blue shifted, 0.33 eV red shifted, and 0.07 eV red shifted compared to the computational results respectively). In all cases, the difference between the calculated and experimental bands are within the limits of accuracy of the TD-DFT approach for the PBE0 method ($\Delta E = \pm 0.2-0.3$ eV for singlet excitations and up to 0.5 eV for triplet excitations). $^{39}$ The intensities of the calculated bands after 400 nm (red line, Figure 6) is the same relative to the experimental UV bands (blue line, Figure 6). The opposite behaviour was observed the simulated absorption spectrum of spiro-MeOTAD as compared to the experimentally obtained UV-Vis absorbance. $^{40}$ As shown by Zhang et al, the +2 oxidation state of spiro-MeOTAD can absorb around 2000 nm. $^{36}$ This behaviour was also observed in the SFX-MeOTAD$^{31}$ calculations, where a peak was observed at 1937 nm and corresponds to the transitions between the HOMO-18 orbital to the LUMO+10 orbital (see S5 for visualised MO transitions for SFX-MeOTAD$^{31}$). This band was not able to be measured experimentally due to the limitations of the equipment. $^{39}$

Figure 6: Comparison of experimental (thin film [blue] and solution [magenta]) and computational absorption (red) spectra for SFX-MeOTAD$^{39}$

Figure 7: Computational absorption spectrum for SFX-MeOTAD$^{4}$
When doping SFX-MeOTAD with the dicationic salt of SFX-MeOTAD the following mechanism is assumed to take place, in analogy to spiro-MeOTAD\textsuperscript{35}:

\[
\text{SFX-MeOTAD}^{2+} + \text{SFX-MeOTAD} \rightarrow 2 \text{SFX-MeOTAD}^{4+}
\]

Therefore, TD-DFT calculations were conducted on the monocation of SFX-MeOTAD and calculated absorption spectrum showed peaks at 454 nm and 611 nm, see Figure 7. There is also a peak at 360 nm thus showing there has been a blue shift in the absorbance bands as compared to the neutral species. The band at wavelength 454 nm corresponds to transitions that occur in the \( \alpha \) manifold orbitals from HOMO orbitals, HOMO-2a orbital to the LUMO\( \alpha \), whereas the band at 611 nm corresponds to the transitions occurring at the low-lying HOMO-7\( \beta \)/HOMO-8\( \beta \) to the LUMO\( \beta \) orbital. These show local excitation character in one of the triarylamine groups in the fluorene portion of the core but there is also some partial CT character as well. When compared to the experimental results from Figure 2 (c), the bands present at ca. 520 nm and ca. 680 nm, the values obtained through the computational methods are in agreement with the experimental values and fall into the limits of accuracy expected from using the PBE0 method.\textsuperscript{39}

When comparing the intensities of the computed spectra it can be seen that the intensity of the absorption bands at ca. 450 nm and ca. 680 nm are much higher for the +2 species than the +1 species (see S6 for visualised MO transitions for SFX-MeOTAD\textsuperscript{8}).

From the above experimental and calculated data and using the equation for oxidising SFX-MeOTAD with a dicationic salt we can extrapolate that as we increase the concentration of the dicaticonic salt, for concentrations that are below 50% dopant all the SFX-(TFSI)\textsubscript{2} is utilised to convert the neutral SFX-MeOTAD to the monocation so this gives rise to the increase in intensity of the dicationic salt, for concentrations that are above 50% dopant all the SFX-(TFSI)\textsubscript{2} is utilised to convert the neutral SFX-MeOTAD to the LUMO\( \alpha \) orbital to the LUMO\( \beta \), 522 nm. For concentrations over 50%, there is an excess of the dication, therefore this describes the increase in the band ca. 680 nm. This means that for the optimal dopant concentration of 20.5%, all of the dicaticonic salt is used to convert the neutral SFX-MeOTAD to the SFX-MeOTAD monocation. Using the redox potentials known for SFX-MeOTAD, the doping efficiency of the optimal dopant mol% can be found.\textsuperscript{21} Combining neutral SFX-MeOTAD and the dicaticonic salt would result in a compositional mixture containing neutral, monocation and dication species at equilibrium. The equilibrium constant of the redox reaction was calculated using the Nernst equation and thus the contribution of each species can be calculated. See S10 in SI for the full calculation. From the calculation a solution that initially contained neutral SFX-MeOTAD and 20.5 mol% SFX-(TFSI)\textsubscript{2} should have almost no dication species at equilibrium. The final concentrations of the individual species in this optimal dopant mol% are 59.08%, 40.84% and 0.08% for neutral, monocation and dication respectively. Taking this into account we were able to create a computational absorption spectrum, using the oscillator strengths and their corresponding wavelengths, of the 20.5% doped sample (redline, Figure 8). See S7-S9 in SI for full list of oscillator strengths and corresponding orbital contributions.

For the calculated maximum absorption bands were found to be 389 nm, 459 nm and 681 nm. When compared to the experimental data (thin film (blue) and solution (magenta), Figure 8), these values are in excellent agreement as the difference between the calculated and experimental bands are within the limits of accuracy of the TD-DFT approach (band 1 \( \Delta E=\pm0.16 \) eV (solution), \( \Delta E=\pm0 \) eV (thin film); band 2 \( \Delta E=\pm0.32 \) eV (solution), \( \Delta E=\pm0.32 \) eV (thin film) and band 3 \( \Delta E=\pm0.07 \) eV (solution), \( \Delta E=\pm0.05 \) eV (thin film)).\textsuperscript{39} As mentioned above, a simplistic picture proposed earlier for spiro-MeOTAD was assumed to be true for the SFX-MeOTAD as well, where it is assumed that all the dicaticonic salt is used to convert SFX-MeOTAD into its monocation. However, conversion of SFX-MeOTAD\textsuperscript{2+} to SFX-MeOTAD\textsuperscript{4+}, as proposed by Zhang et al\textsuperscript{36}, cannot be ruled out. DFT and TD-DFT computational calculations were also carried out for the +4 triplet, and absorbance maxima were found at ca. 630 nm and ca. 760 nm. These peaks were not seen in the experimental data of the

![Figure 8](image)

**Figure 8:** Comparison of experimental [thin film (blue) and solution (magenta)] and computational absorption spectra (red) for 20.5% SFX-(TFSI)\textsubscript{2} doped SFX-MeOTAD.

![Figure 9](image)

**Figure 9:** C1s, F1s, N1s and O1s corresponding to undoped SFX-MeOTAD [0%], SFX-MeOTAD doped with 10 mol% SFX(TFSI)\textsubscript{2} [10%], SFX-MeOTAD doped with 20 mol% SFX(TFSI)\textsubscript{2} [20%] and SFX (TFSI)\textsubscript{2} dopant [100%].
doped samples [Fig. 2(c)], therefore we can assume that +4 SFX-MeOTAD is not present in the measured films.

3.2 Electronic Properties of SFX(TFSI)2 doped SFX-MeOTAD

X-ray photoelectron spectroscopy (XPS) is a highly surface-sensitive, element-specific technique which was used to probe the variation in local chemistry around carbon, nitrogen and oxygen atoms as a result of nearest-neighbour interaction during doping of SFX-MeOTAD with different concentrations of SFX(TFSI)2. High resolution core level XPS spectra were acquired and deconvoluted to understand the effect of the dopant and mechanism of dopant-HTM interaction. Fig. 9 compares the (a) C1s, (b) F1s, (c) O1s and (d) N1s core level XPS spectra of pristine SFX-MeOTAD [0%], SFX-MeOTAD doped with 10 mol% SFX(TFSI)2 [10%], and 20 mol% SFX(TFSI)2 [20%] and the dopant SFX(TFSI)2 [100%]. The C1s spectra of all the samples have been deconvoluted into five components each as shown in Figure 9 (a), namely C–H, C=C/C=C, C=N/C=O, Ca–O–C, and C–π* at 284.5 ± 0.1 eV, 285.5 ± 0.1 eV, 286.4 ± 0.2 eV, 287.3 ± 0.3 eV and 291.5 eV, respectively corresponding to peak position for Spiro-MeOTAD 18. The peak at 285.5 eV is expected to have a contribution from both sp2 and sp3 hybridised carbon since the disorder-induced peak (sp3) occurs at 0.5 eV higher binding energy than the graphitic (sp2) peak 41 but cannot be resolved using the 0.9 eV resolution XPS equipment used in this study. The 287.3 eV peak has a contribution from both C-N and C-O bonds whereas the C–π* plasmon feature which originates from the delocalisation of electron density over the carbon atoms and is a signature of the aromatic nature of the molecule is reported at ~291.5 eV. In SFX(TFSI)2 doped SFX-MeOTAD spectra, broadening of the 291.5 eV peak can also be attributed to the presence of CF3 groups in TFSI anions since it has not been possible to deconvolute the effect of π–π* and CF3. The fitting parameters extracted from the core level XPS spectra of pristine and SFX(TFSI)2 doped SFX-MeOTAD are summarised in Table S11 in the SI. A decrease in percentage of the C–H component is observed from pristine SFX-MeOTAD (46.7%) to 10 mol% doped sample (41.4%) before increasing again in the case of 20 mol% (45.4%) whereas pure SFX(TFSI)2 records the lowest C–H percentage at 41.2%. The initial reduction in C–H component is assigned to the air-exposure of the samples prior to measurements being undertaken as in the case of Spiro-OmeTAD.18 There is negligible variation in the C=C/C=C component upon addition of 10 mol% dopant but the contribution of carbon bonded to carbon increases from 29.9% for undoped SFX-MeOTAD to 33.7% for 20 mol% doped sample, which is possibly due to the complex formation between SFX-MeOTAD and SFX(TFSI)2 dopant or oxidised SFX-MeOTAD+ species. The increase in C=N/C=O component from SFX-MeOTAD to 10 mol% SFX(TFSI)2 sample before reducing for 20 mol% SFX(TFSI)2 sample can be corroborated with the variation in local chemistry due to additional nitrogen environment from SFX(TFSI)2 dopant and follows the N K-edge resonances as will be discussed later. Increase in % concentration of aromatic carbon Ca–O–C component initially upon doping with 10% SFX(TFSI)2 could be an indication of the oxidation of molecules.
resonances occur due to transitions from the core level to the unoccupied antibonding π molecular states (1s→2p), whereas the σ resonances occur because of transitions of core electrons to different antibonding σ molecular states. Five π* resonances at 285.6, 286.7, 287.4, 289.0 and 290.6 eV and four σ* resonances at 292.1, 294.4, 298.6 along with a broad band at 303.0 eV are observed.

The I1, I2, I4 and I8 resonances can be assigned to transitions from C2, 3→π* (a2) and C2, 4→π* (b1), C1 to the π* (b1), C1, 3, 4 to π* and C1→π*(b1) orbitals, respectively. Resonance I3 at 287.5 eV has contribution from C1s→π* (C-H) with some σ* C-H/3p Rydberg-like excitations (details of the assignments provided in Table S12 in SI). The resonance between 286-287.4 eV may have multiple contribution from N-substituted aromatic C which is often reported to be overlapped with oxygen moieties. Significant broadening of the π* resonances, the low atomic concentration of nitrogen and the overlap with the C-O features, may result in lack of any clear signature of C-N at the K-edge spectra. Table S7 summarises the peak positions and assignments of the C K-edge NEXAFS resonances of SFX-MeOTAD and SFX-MeOTAD doped with SFX(TFSI).

The C K-edge spectra of SFX-MeOTAD, SFX-MeOTAD doped with different concentrations of SFX(TFSI)2 and pure SFX(TFSI)2 consist of the same number of absorption bands which have close energy positions but variation in intensities are clearly discernible [Figure 10 (a)]. This intensity variation stems from the change in π* and σ* states of SFX-MeOTAD upon doping with SFX(TFSI)2. The strong interaction between the localized π* and σ* states in aromatic molecules give rise to significantly separated energy and two or more degenerate states, resulting in splitting of the π* antibonding orbitals. Intensity of the first π* feature increases significantly upon using SFX(TFSI)2 as a dopant compared to pristine SFX-MeOTAD as observed from Figure 10 (b) which is also evident from the increase in the Iπ*/Iσ*, ratio from 100 % at 0.92 to 1.32 for 10% sample [Figure 10 (c)]. This would suggest an increase in the aromaticity of the molecules when the pre-oxidised form of SFX-MeOTAD is used as a dopant. However, increasing the concentration of the dopant to 20% affects the Iπ*/Iσ*, ratio adversely, evident from a decrease in value to 1.26. Moreover, Iπ*/Iσ*, ratio is reportedly highest at 1.38 for pristine 0% doped samples. It can be proposed that SFX-MeOTAD forms a charge transfer complex with SFX(TFSI)2 during the doping procedure, which probably has several decay channels available for π* transitions due to the electron-donating methoxy groups in undoped samples and the nitrogen-based counterion, (TFSI) in the dopant. This results in a decrease in the Iπ*/Iσ*, ratio from pristine to doped samples. However, the increase in the dopant concentration possibly results in localisation of the charge density due to enhanced concentration of TFSI anions, which in turn reduces the π* and σ* intensities. A similar phenomenon is observed in case of Spiro(TFSI)2, where intermolecular charge transfer is hindered as well as orbital overlap and π-π interaction due to the anions involved in the molecules.64 Significant broadening of I1 in the case of 100% dopant implies delocalisation of π* orbitals. The variation in line shape may also suggest the difference in charge transfer in 100% dopant and other doping concentrations. TFSI is a good nitrogen-based counterion due to the anionic charge being appreciably delocalised over the bis(sulfonylimide) imide moiety. The electron-withdrawing inductive effect of the CF3 groups along with the electron-donating methoxy moieties have a synergistic effect on the charge transfer properties of the dopant resulting in delocalisation of the charge density over the molecules. However, upon using it as a dopant in SFX-MeOTAD, formation of a complex between them may result in the loss of delocalisation of charge carriers, thereby affecting the broadening of I1. The reduction in intensities of I1, I4 and I8 of 10% and 20% doped sample in comparison to undoped 0% sample may be explained in terms of the fact that the presence of an electron negative nearest neighbour to carbon may make the π* orbital non-degenerate which reduces the probability of transitions from C1s→π* (C-H), C1s→π*(C2,3,4) and π*(C1). The transitions from C1s→σ* molecular orbitals give rise to the σ* shape resonances beyond 291.0 eV and are significantly broader as a result of multiple transitions or interaction of the in-plane carbon orbitals. The π* resonances, Iσ, I1, I4 and I8 have been assigned to σ*C=C + σ*C-N 51,55, σ*C → contribution from b2g π* shake-up character, σg and σ* C=C 43,44,56-62 transitions, respectively. The resonance at 292.1 eV may have a contribution from σ*C=C+61-66 in case of 100%, 10% and 20% doped sample. An overall enhancement in intensity of σ* resonances has been observed upon doping SFX-MeOTAD with SFX(TFSI)2. Thus, it can be proposed that doping SFX-MeOTAD with SFX(TFSI)2 helps in enhancing the aromatic nature of the molecule initially but increasing the dopant concentration further detrimentally affects the aromaticity and possibly the π stacking. The conductivity values of the doped samples follow a similar trend, where the conductivity increase with increase in the dopant concentration till around 20.5 mol% above which it plateaus. This suggests that the choice of counterion of the dopants for HTMs is crucial since the counterions can interact
strongly with the oxidised HTM molecules and affect conductivity. So, a wider range of counterions should be explored when optimising the dopants for triarylamine based HTMs. Thus, the choice of counterion is something that needs to be considered when exploring new hole transport materials. This has been observed in some studies reported in literature. For example, larger aggregation was observed when Na⁺ was used as counterion in conjugated polyelectrolytes containing n-decylated backbone with charged pendant groups as compared to the same material having CH₃NH₂⁺ counterion. PSCs fabricated utilising these hole transport materials showed that devices made with HTM containing Na⁺ counterion were around 50% less efficient than devices made using HTM with CH₃NH₂⁺ counterion. An improvement in hole conductivity and homogeneity was observed in an ionic type HTM containing TFSI⁻ counterion as compared to the same HTM that did not contain the counterions. Counters used in ionic liquids such as PF₆⁻, CF₃SO₃⁻ and BF₄⁻ are also found in conducting polymers used for photovoltaic applications because the counterions are weakly interacting due to a shielded charge. A halide counterion (Br⁻) in A-D-A type ionic molecule as HTM was compared with the same HTM with TFSI⁻ counterions. It was found that HTMs with the TFSI⁻ counterions showed better performance in PSCs as compared to those with Br⁻ as counterion. Although devices made with the TFSI⁻ containing HTM exhibited higher efficiencies, the performance of devices using HTM with Br⁻ counterions was still better than that of devices where the HTM did not contain any counterions. This is because the HOMO is located at a deeper energy level due to the high electron withdrawing effect of the quarternary part of the HTM that helps to modify the HOMO.

From the results obtained in the present study the optimal doping concentration is 20.5% as this is where the conductivity values started to plateau. It is important to note that the doping affects not only the conductivity but also the other properties like hydrophobicity, energy levels, as well as film processing ability etc., and hence the best performing devices might not always correspond to the optimal doping. Upon using the spiro-(TFSI)2 as a dopant, a downshift in the ionization potential of spiro-OMeTAD was observed. The best performing device was shown with 14 mol% spiro-(TFSI)2. At the optimal dopant concentration, the hydrophobicity of the film was shown to increase as the contact angle increases from 72.2° for the Li-TFSI doped spiro-OMeTAD to 83.3° for the spiro-OMeTAD with optimal spiro-(TFSI)2 doping. Cross-sectional SEM imaging showed that voids appeared in the Li-TFSI doped spiro-OMeTAD devices after aging for 300 hours at 50 °C but this was not observed in the optimal spiro-(TFSI)2 devices. These observations showed that the spiro-(TFSI)2 doped films have a greater stability in high moisture and oxygen environments. When (MeO-TPC)TFSI was used as dopant, the conductivity of spiro-OMeTAD increased drastically at 50% dopant but the best performing device was made with 30% dopant with an efficiency of 17.9%. The contact angle also increased showing that the film hydrophobicity increased. The film morphology showed that there were no visible cracks or aggregation of the film unlike the film made with FK209. Using acid additives to help to enhance the conductivity of spiro-OMeTAD, was observed to decreases the ionisation energy of the HTM and also decreases the Fermi level. There was no noticeable change in the ionization energy and Fermi level between spiro-OMeTAD doped with LiTFSI and cobalt (III) complexes and those that has the acid additives. It was concluded that the increases in conductivity was due to hydrogen-bonding that increases the delocalization of electrons. NEXAFS studies have also been carried around the N K-edge to understand the effect of SFX(TFSI)2 doping on SFX-MeOTAD. The positions and assignments of the N K-edge resonances of pristine and doped samples are summarized in Table S13 in SI. N K-edge NEXAFS spectra of samples analyzed are shown in Figure 11 and are dominated by four resonances at 401.1, 402.7, 405.1 and 407.7 eV. Splitting of the N1s→π* resonance in 10%, 20% and 100% samples may be attributed to the difference in bond length between the N-C molecules as has been previously observed for Spiro-MeOTAD and SFX-MeOTAD in this study. A modest difference in C-N bond length in the case of Spiro(TFSI)2 has been reported and a similar variation in bond length in case of SFX(TFSI)2 has been observed in this study [Table 1]. This trend would corroborate the fact that the presence of the electron-donating methoxy groups affects the charge density of the molecules and plays a crucial role in influencing the charge transfer process. The resonance at 402.9 eV can be attributed to transitions to antibonding orbitals localised on amine moieties. An increase in the area under the curve from the pristine 0% to 10% and 20% doped sample signifies an enhancement in the nitrogen content of the molecules as the edge-jump intensity is proportional to the total nitrogen content in the molecules. SFX(TFSI)2 can have multiple nitrogen environments stemming from the different oxidation potential on the amine N in the two halves of SFX-MeOTAD and the nitrogen from the dopant. The substantial enhancement in the nitrogen content of doped molecules point towards an increase in π* and n* density of states (DOS) over nitrogen and may also indicate the presence of additional decay channels available to the 10% and 20% via formation of a charge transfer complex similar in lines to the Spiro-MeOTAD/TFSI⁻ which creates additional DOS over N through the (CF₃SO₂)⁺N⁻ counterion in Spiro(TFSI)2. Pristine 0% sample has the lowest area under the curve due to the lower nitrogen environment available compared to 10%, 20% and 100% samples. Interestingly, increasing the dopant concentration beyond 10% shows a decrease in the area under the curve which can probably be associated with the localisation of charge density due to enhanced TFSI⁻ concentration and can be corroborated with the C K-edge spectra where the aromaticity is found to decrease upon using a dopant concentration beyond 10%. (Figure 10).

Thus, it can be concluded that doping SFX-MeOTAD with SFX(TFSI)2 results in an enhancement in the aromatic nature which might possibly suggest improved π stacking between the molecules until an optimal concentration is reached, at which point a decrease in these is observed.
4. Conclusion

This study presents a detailed investigation into the modifications in the molecular structure, electronic and optical properties of SFX-MeOTAD by doping it with its pre-oxidised form viz., a dicaticonic salt SFX(TFSI)$_2$, probed using XPS, NEXAFS and detailed DFT, TD-DFT computational calculations. By varying doping concentration of the dicaticonic salt over a larger range [0-100%], it was possible to find the optimal doping concentration which resulted in four orders of increase in the conductivity of the pristine SFX-MeOTAD. An optimal doping concentration of 20.5% SFX(TFSI)$_2$ resulted in films with a conductivity of 9.43×10$^{-4}$ S cm$^{-1}$. Computational calculations gave detailed understanding of the geometrical structure, electronic and optical properties of SFX-MeOTAD and its oxidised forms. This allowed us to computationally calculate the absorbance spectrum for SFX-MeOTAD doped with the optimal dopant concentration of 20.5% SFX(TFSI)$_2$. XPS results reveal that doping with SFX(TFSI)$_2$ not only results in oxidation of SFX-MeOTAD but also variation in the local chemistry around carbon and nitrogen which would influence the conductivity of the doped films. Indicating that the counterion of the dopant can strongly interact with the oxidised HTM molecules and affect conductivity. Doping SFX-MeOTAD with SFX(TFSI)$_2$ helps in enhancing the aromatic nature of the molecule initially but increasing the dopant concentration further affects the aromaticity and possibly the π stacking. The conductivity values of the doped samples follow a similar trend. Based on the results of the present study, the following considerations are important for doping triarylamines based HTM for perovskite solar cells a) proper choice of the counterion in the dopant as it interacts strongly with the HTM, b) although the HTM may contain multiple triarylamines, each molecule is likely to be no more than singly charged at the optimal dopant concentration, and c) optimising the dopant concentration will strongly affect the conductivity.

Conflicts of interest

There are no conflicts to declare.

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